

Pb Free Plating Product

MBR1035CA thru MBR10200CA



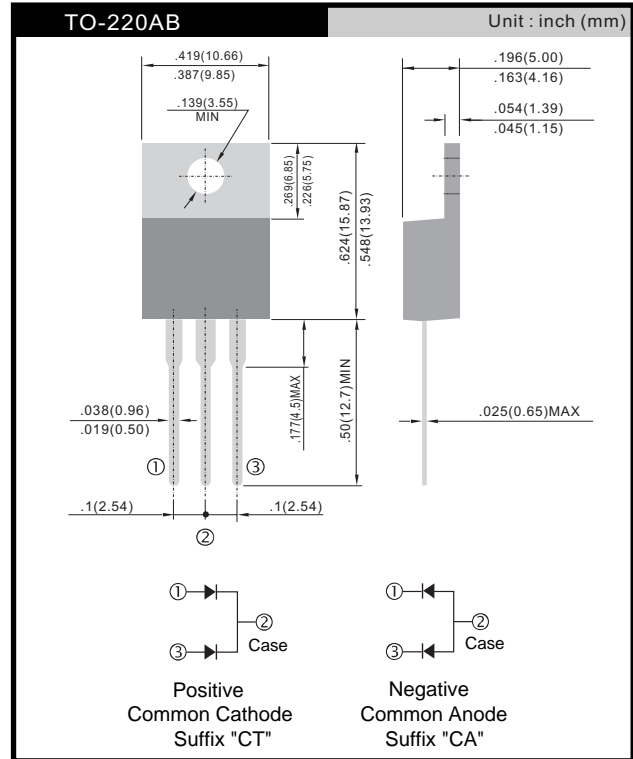
10.0 Ampere Dual Common Anode Schottky Barrier Rectifier Diodes

Features

- ✧ Plastic material used carriers Underwriters Laboratory Classification 94V-0
- ✧ Metal silicon junction, majority carrier conduction
- ✧ Low power loss, high efficiency
- ✧ High current capability, low forward voltage drop
- ✧ High surge capability
- ✧ For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- ✧ Guard-ring for overvoltage protection
- ✧ High temperature soldering guaranteed: 260°C/10 seconds, 0.25"(6.35mm) from case

Mechanical Data

- ✧ Cases: JEDEC TO-220AB molded plastic body
- ✧ Terminals: Pure tin plated, lead free, solderable per MIL-STD-750, Method 2026
- ✧ Polarity: As marked
- ✧ Mounting position:Any
- ✧ Mounting torque: 5 in. - lbs, max
- ✧ Weight: 2.0 gram approximately



Maximum Ratings and Electrical Characteristics

Rating at 25 °C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Type Number	Symbol	MBR 1035 CA	MBR 1045 CA	MBR 1050 CA	MBR 1060 CA	MBR 1090 CA	MBR 10100 CA	MBR 10150 CA	MBR 10200 CA	Units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	35	45	50	60	90	100	150	200	V
Maximum RMS Voltage	V_{RMS}	24	31	35	42	63	70	105	140	V
Maximum DC Blocking Voltage	V_{DC}	35	45	50	60	90	100	150	200	V
Maximum Average Forward Rectified Current	$I_{F(AV)}$	10								A
Peak Repetitive Forward Current (Rated VR, Square Wave, 20KHz)	I_{FRM}	10								A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I_{FSM}	120								A
Peak Repetitive Reverse Surge Current (Note 1)	I_{RRM}	1.0		0.5						A
Maximum Instantaneous Forward Voltage at (Note 2) IF=5A, TA=25°C IF=5A, TA=125°C IF=10A, TA=25°C IF=10A, TA=125°C	V_F	0.70 0.57 0.80 0.67		0.80 0.65 0.90 0.75		0.85 0.75 0.95 0.85		0.88 0.78 0.98 0.88		V
Maximum Instantaneous Reverse Current @ TA=25 °C at Rated DC Blocking Voltage @ TA=125 °C	I_R	0.1								mA
		15		10		2		5		mA
Voltage Rate of Change (Rated V_R)	dV/dt	10,000								V/us
Maximum Typical Thermal Resistance	$R_{\theta JC}$	1.5								°C/W
Operating Junction Temperature Range	T_J	- 65 to + 150								°C
Storage Temperature Range	T_{STG}	- 65 to + 175								°C

Note 1: 2.0uS Pulse Width, f=1.0KHz

Note 2: Pulse Test : 300uS Pulse Width, 1% Duty Cycle

RATINGS AND CHARACTERISTIC CURVES (MBR1035CA thru MBR10200CA)

FIG. 1- FORWARD CURRENT DERATING CURVE

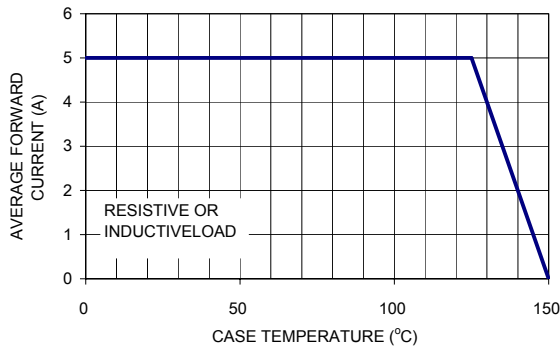


FIG. 2- MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

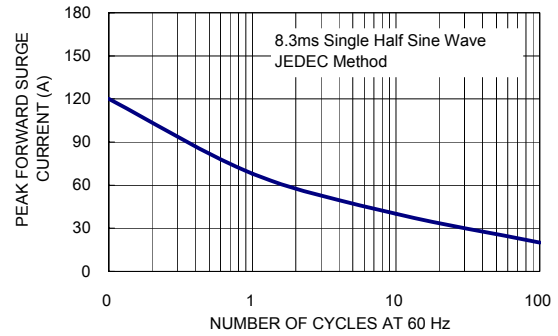


FIG. 3- TYPICAL FORWARD CHARACTERISTICS

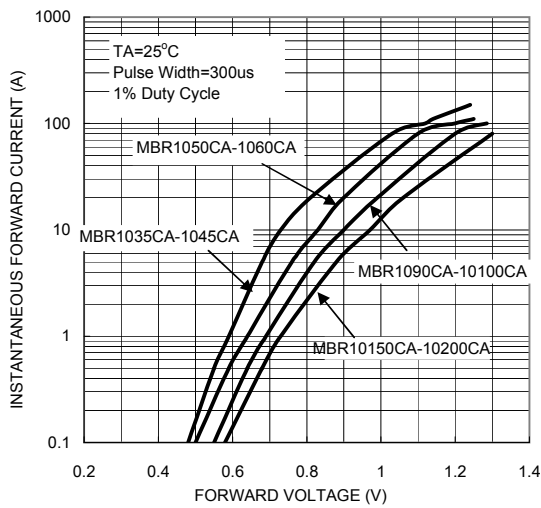


FIG. 4- TYPICAL REVERSE CHARACTERISTICS

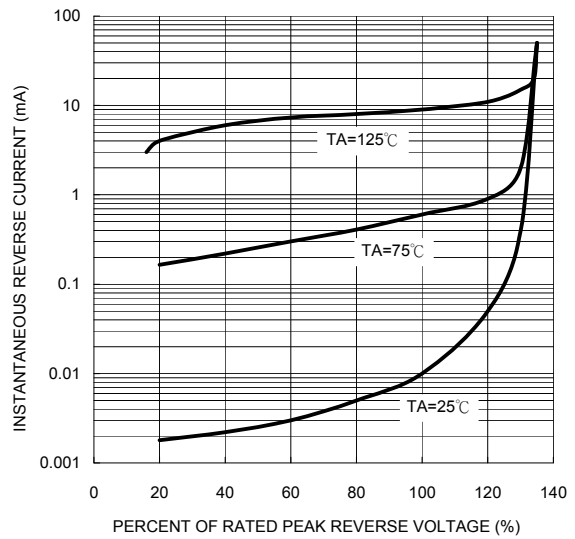


FIG. 5- TYPICAL JUNCTION CAPACITANCE

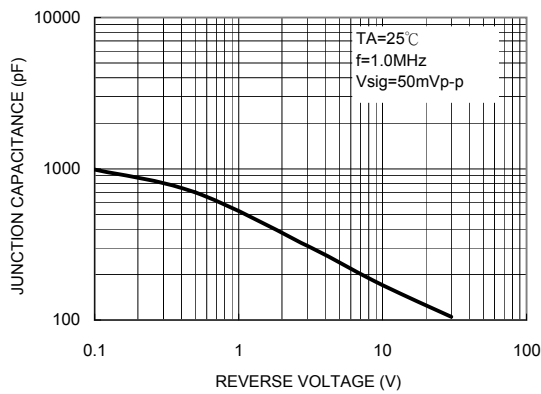


FIG. 6- TYPICAL TRANSIENT THERMAL CHARACTERISTICS PER LEG

